

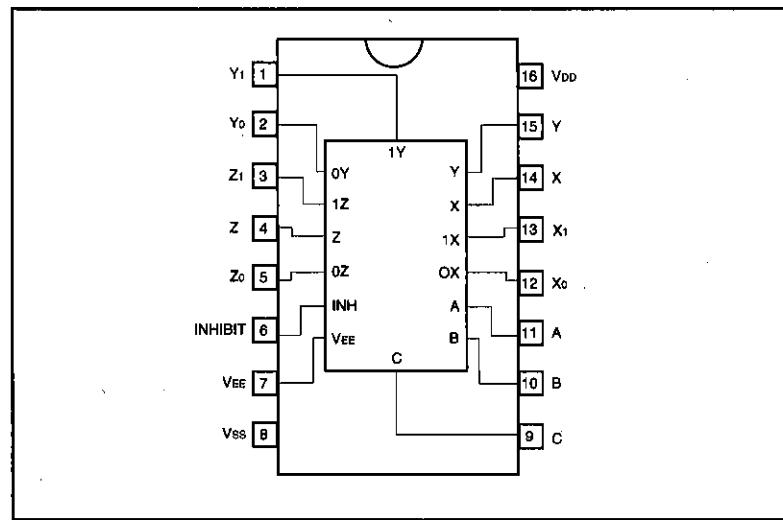
# Triple 2-channel analog multiplexer/demultiplexer

## BU4053BC/BU4053BCF/BU4053BCFV

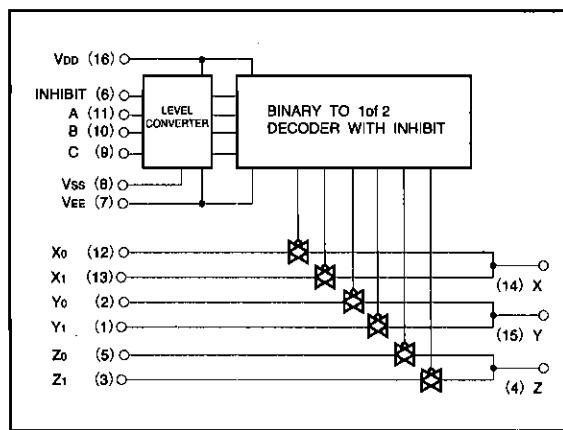
The BU4053BC, BU4053BCF, and BU4053BCFV are multiplexers/ demultiplexers capable of selecting and combining analog signals and digital signals in a 2 ch × 3 configuration. Inhibit signals and control signals are used to turn on the switch corresponding to each of the channels. In addition, even if the logical amplitude ( $V_{DD}-V_{SS}$ ) of the control signal is low, signals with a large amplitude ( $V_{DD}-V_{EE}$ ) can be switched.

Also, as each switch has a low ON resistance, it can be connected to a low impedance circuit.

●Block diagram



●Logic diagram



●Truth table

INHIBIT	A	B	C	ON SWITCH
L	L	L	L	X <sub>0</sub> Y <sub>0</sub> Z <sub>0</sub>
L	H	L	L	X <sub>1</sub> Y <sub>0</sub> Z <sub>0</sub>
L	L	H	L	X <sub>0</sub> Y <sub>1</sub> Z <sub>0</sub>
L	H	H	L	X <sub>1</sub> Y <sub>1</sub> Z <sub>0</sub>
L	L	L	H	X <sub>0</sub> Y <sub>0</sub> Z <sub>1</sub>
L	H	L	H	X <sub>1</sub> Y <sub>0</sub> Z <sub>1</sub>
L	L	H	H	X <sub>0</sub> Y <sub>1</sub> Z <sub>1</sub>
L	H	H	H	X <sub>1</sub> Y <sub>1</sub> Z <sub>1</sub>
H	X	X	X	NONE

X : Don't Care

## ●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits		Unit
Power supply voltage	V <sub>DD</sub> - V <sub>EE</sub>	-0.3~20		V
Power dissipation	P <sub>d</sub>	1000 (DIP), 500 (SOP), 400 (SSOP)		mW
Operating temperature	T <sub>opr</sub>	-40~85		°C
Storage temperature	T <sub>stg</sub>	-55~150		°C
Input voltage	V <sub>IN</sub>	-0.3~V <sub>DD</sub> +0.3		V

## ●Electrical characteristics

DC characteristics (unless otherwise noted, Ta=25°C, V<sub>EE</sub>=V<sub>SS</sub>=0V)

Parameter	Symbol	Min.	Typ.	Max.	Unit	V <sub>DD</sub> (V)	Conditions	Measurement Circuit
High-level input voltage	V <sub>IH</sub>	3.5	—	—	V	5	—	Fig.1
		7.0	—	—		10		
		11.0	—	—		15		
Low-level input voltage	V <sub>IL</sub>	—	—	1.5	V	5	—	Fig.1
		—	—	3.0		10		
		—	—	4.0		15		
High-level input current	I <sub>IH</sub>	—	—	0.3	μA	15	V <sub>IH</sub> =15V	Fig.1
Low-level input current	I <sub>IL</sub>	—	—	-0.3	μA	15	V <sub>IL</sub> =0V	Fig.1
R <sub>ON</sub> resistance	R <sub>ON</sub>	—	—	950	Ω	5	—	Fig.2
		—	—	250		10		
		—	—	160		15		
R <sub>ON</sub> resistance deflection	△R <sub>ON</sub>	—	25	—	Ω	5	—	Fig.2
		—	10	—		10		
		—	5	—		15		
OFF-channel leakage current	I <sub>OFF</sub>	—	—	0.3	μA	15	—	Fig.3
		—	—	-0.3		15		
Quiescent supply current	I <sub>DD</sub>	—	—	5	μA	5	V <sub>i</sub> =V <sub>DD</sub> or GND	—
		—	—	10		10		
		—	—	15		15		

Switching characteristics (unless otherwise noted,  $T_a=25^\circ\text{C}$ ,  $V_{EE}=V_{SS}=0\text{V}$ ,  $R_L=1\text{k}\Omega$ ,  $C_L=50\text{pF}$ )

Parameter	Symbol	Min.	Typ.	Max.	Unit	$V_{DD}$ (V)	Conditions	Measurement Circuit
Propagation delay time Switch IN → OUT	$t_{PLH}, t_{PHL}$	—	15	45	ns	5	—	Fig.4
		—	8	20		10		
		—	6	15		15		
Propagation delay time CONT → OUT	$t_{PHZ}, t_{PLZ}$ $t_{PZH}, t_{PZL}$	—	170	550	ns	5	—	Fig.5, 6
		—	90	240		10		
		—	70	160		15		
Propagation delay time INH → OUT	$t_{PHZ}, t_{PLZ}$ $t_{PZH}, t_{PZL}$	—	170	450	ns	5	—	Fig.5, 6
		—	90	210		10		
		—	70	160		15		
Max. propagation frequency	$f_{Max.}$	—	15	—	MHz	5	$V_{EE}=-5\text{V}$ *1	Fig.7
Feedthrough attenuation	$FT$	—	0.7	—	MHz	5	$V_{EE}=-5\text{V}$ *2	Fig.7
Sinewave distortion	$D$	—	0.02	—	%	5	$V_{EE}=-5\text{V}$ *3	Fig.7
Input capacitance (control)	$C_C$	—	5	—	pF	—	—	—
Input capacitance (switch)	$C_S$	—	10	—	pF	—	—	—

\*1  $V_{IN}=5\text{Vp-p}$  sine wave, frequency that enables  $20 \log_{10} \frac{V_{OUT}}{V_{IN}} = -3 \text{dB}$

\*2  $V_{IN}=5\text{Vp-p}$  sine wave, frequency that enables  $20 \log_{10} \frac{V_{OUT}}{V_{IN}} = -50 \text{dB}$  at channel off

\*3  $V_{IN}=5\text{Vp-p}$  sine wave

### Measurement circuits

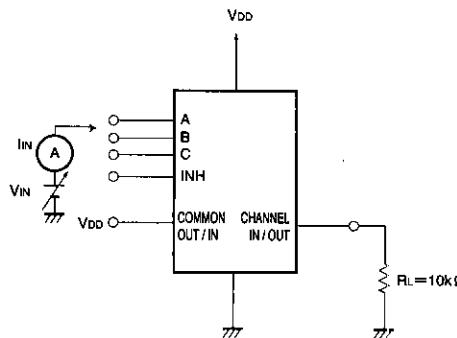


Fig. 1 Input voltage, current

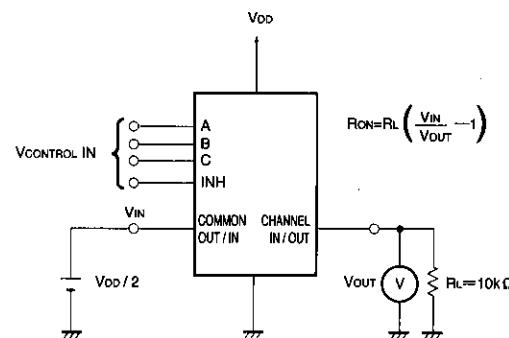


Fig. 2 ON resistance

## ●Measurement circuits

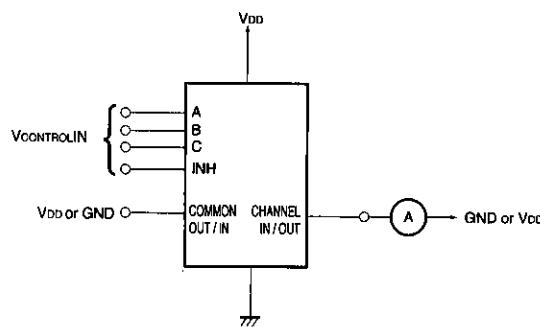


Fig. 3 Channel OFF leakage current

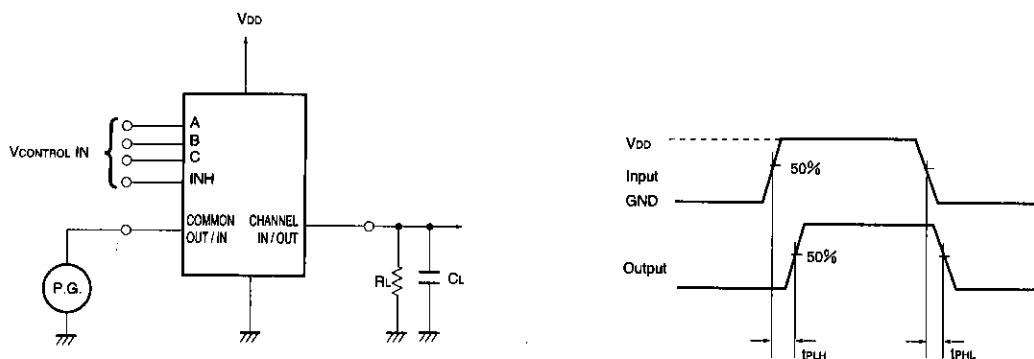


Fig. 4 Propagation delaytime (Switch IN to OUT)

BU4000B series

CMOS logic

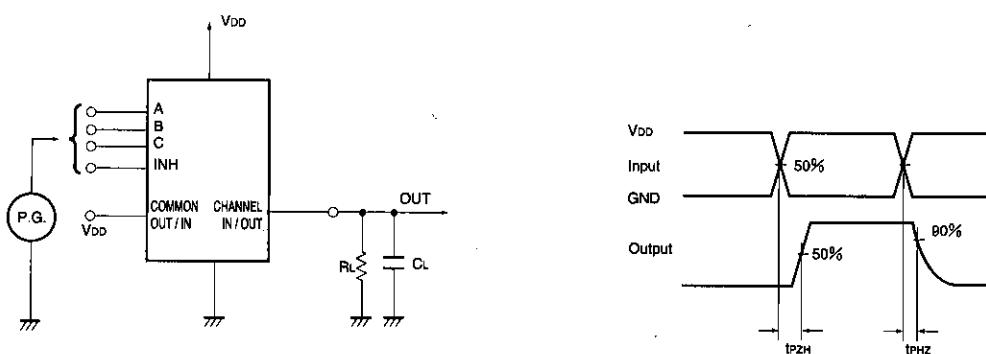


Fig. 5 Propagation delay time (CONT, INH to OUT)

## ● Measurement circuits

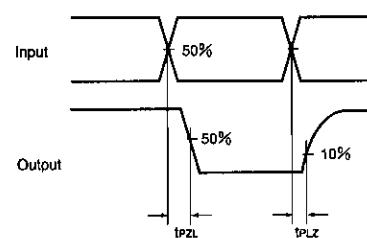
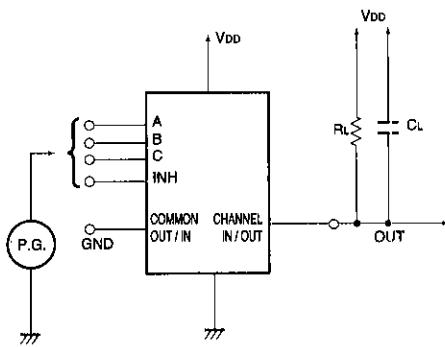


Fig. 6 Propagation delay time (CONT, INH to OUT)

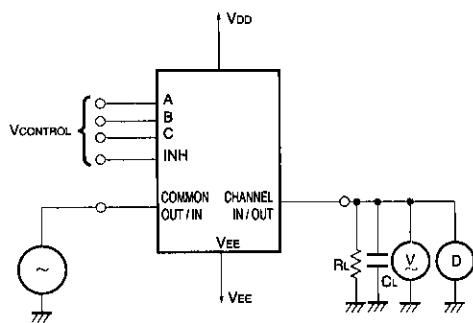


Fig. 7 Maximum propagation frequency, feedthrough, sine wave distortion

## ● Electrical characteristic curve

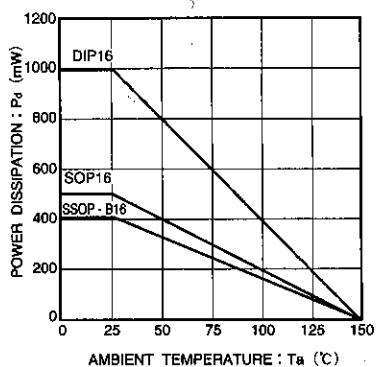
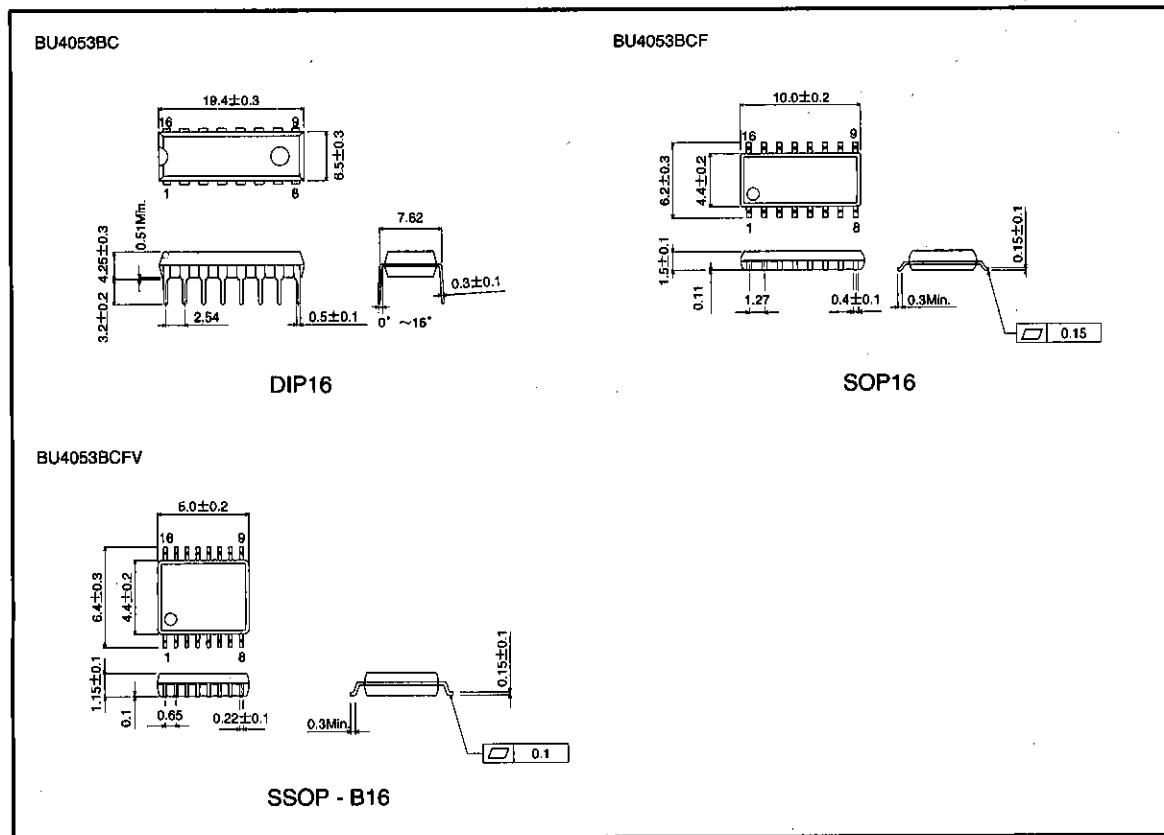


Fig. 8 Power dissipation - Ta characteristic

## ● External dimensions (Units: mm)



BU4000B series

CMOS logic

# Series Standard

## BU4000B

The BU4000 Series are CMOS ICs featuring low voltage and low power consumption. The wide range of operating power supply voltages is compatible with the general-purpose 4000B Series, and when a 5V power supply voltage is used, the LS-TTL IC can be driven directly.

These ICs are available in SOP and SSOP packages as well as the standard DIP package.

### ●Features

- 1) Low power consumption.
- 2) Wide range of operating power supply voltages.
- 3) High input impedance.
- 4) High fan-out.
- 5) Direct drive of 2 L-TTL inputs and 1 LS-TTL input.

### ●Absolute maximum ratings ( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Limits	Unit
Power supply voltage	$V_{DD}$	18 *1	V
Input voltage	$V_{IN}$	-0.3~ $V_{DD}$ +0.3	V
Power dissipation *2	$P_d$	Please refer to specifications for individual package	mW
Storage temperature	$T_{STG}$	-55~150	°C

\*1 For the BU4XXXBC type,  $V_{DD} = 20$  V.

\*2 The values for the SOP and SSOP packages are the values when mounted on a glass epoxy PCB (50 mm x 50 mm x 1.6 mm).

### ●Recommended operating conditions ( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Limits	Unit
Power supply voltage	$V_{DD}$	3~16 *	V
Input voltage	$V_{IN}$	0~ $V_{DD}$	V
Operating temperature	$T_{OPR}$	-40~85	°C

\* For the BU4XXXBC type,  $V_{DD} = 3$  to 18 V.

### ●Electrical characteristic curves

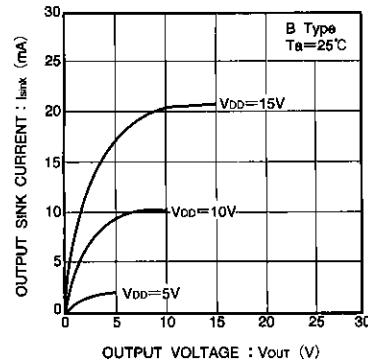


Fig.1 Output sink current - output voltage characteristic

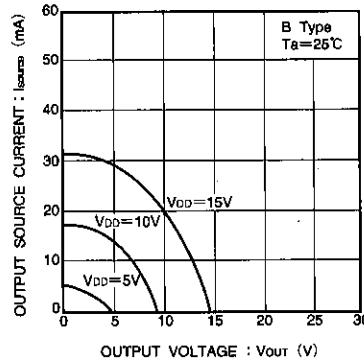


Fig.2 Output source current - output voltage characteristic

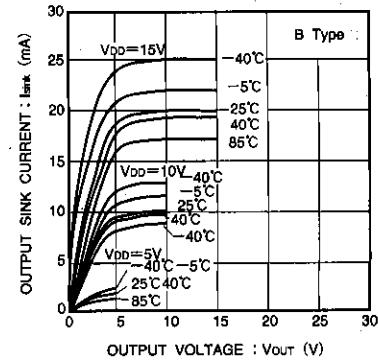


Fig.3 Output SINK current - output voltage characteristic

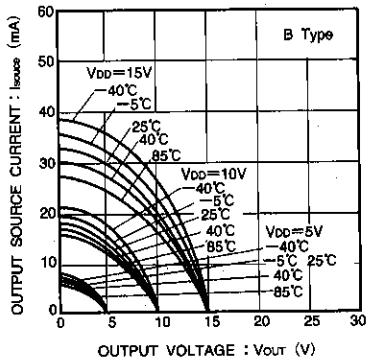


Fig.4 Output source current - output voltage characteristic

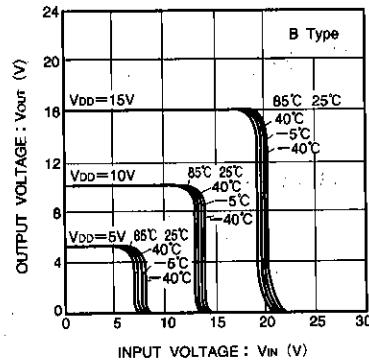


Fig.5 Output voltage - input voltage characteristic

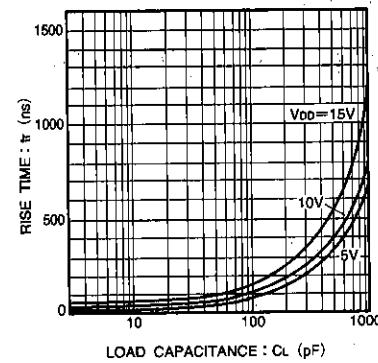


Fig.6 Rise time - load capacitance characteristic

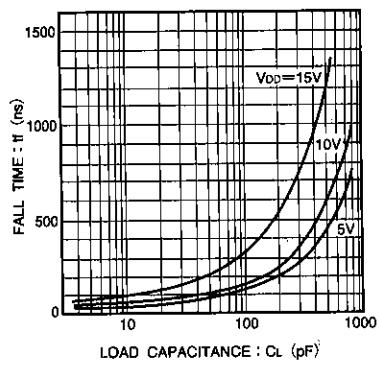


Fig.7 Fall time - load capacitance characteristic

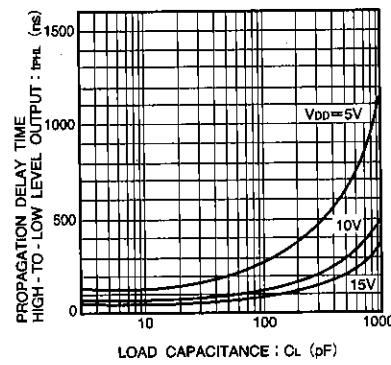


Fig.8 "H" to "L" propagation delay time - load capacitance characteristic

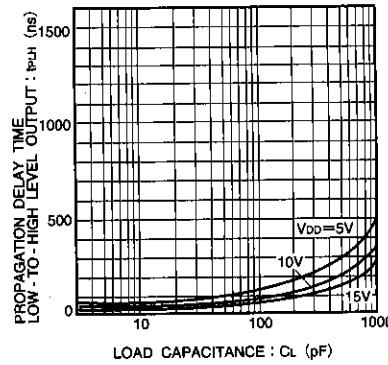


Fig.9 "L" to "H" propagation delay time - load capacitance characteristic

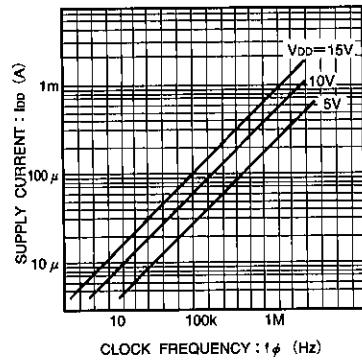


Fig.10 Supply current - clock frequency characteristic

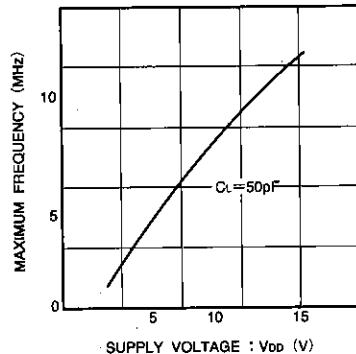


Fig.11 Maximum clock frequency - power supply voltage characteristic

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